

High Voltage Power Operational Amplifiers



FEATURES

- High Voltage 400V (±200V)
- Low Quiescent Current 10mA
- High Output Current 8A
- Programmable Current Limit

APPLICATIONS

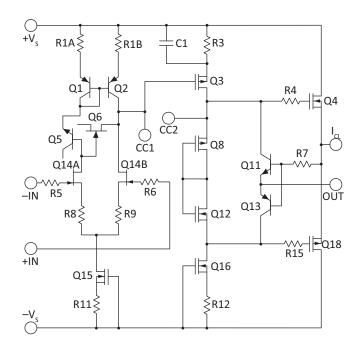
- Piezoelectric Positioning
- High Voltage Instrumentation
- Electrostatic Transducers
- Programmable Power Supplies up to 390V



DESCRIPTION

The PA93 is a high voltage, low quiescent current MOSFET operational amplifier designed as a low cost solution for driving continuous output currents up to 8A and pulse currents up to 14A. The safe operating area (SOA) has no second breakdown limitations and can be observed for all type loads by choosing an appropriate current limiting resistor. The MOSFET output stage is biased AB for linear operation. External compensation provides flexibility in choosing bandwidth and slew rate for the application. Apex Microtechnology's Power SIP uses a minimum of board space allowing for high density circuit boards. The Power SIP is electrically isolated.

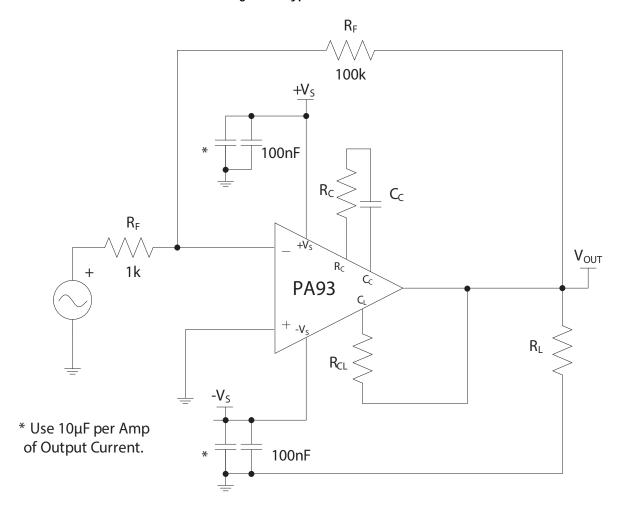
Figure 1: Equivalent Schematic





TYPICAL CONNECTIONS

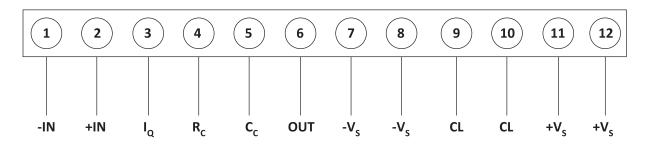
Figure 2: Typical Connections





PINOUT AND DESCRIPTION TABLE

Figure 3: External Connections



Pin Number	Name	Description
1	-IN	The inverting input.
2	+IN	The non-inverting input.
3	IQ	Quiescent current reduction pin. Connect to pin 5 to disable the AB bias. See applicable section
4	RC	Compensation Resistor connection, select value based on Phase Compensation. See applicable section
5	C _C	Compensation Capacitive connection, select value based on Phase Compensation. See applicable section
6	OUT	The output. Connect this pin to load and to the feedback resistors.
7, 8	-V _S	The negative supply rail. Pins 7 and 8 are internally connected.
9, 10	CL	Connect to the current limit resistor. Output current flows into/out of these pins through R_{CL} . The output pin and the load are connected to the other side of R_{CL} . Pins 9 and 10 are internally connected.
11, 12	+V _S	The positive supply rail. Pins 11 and 12 are internally connected.



SPECIFICATIONS

Unless otherwise noted: $T_C = 25$ °C, DC input specifications are \pm value given. Power supply voltage is typical rating. $R_C = 100 C_C = 220 pF$.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Units
Supply Voltage, total	+V _s to -V _s		400	V
Output Current, source, sink, peak, within SOA	I _{OUT}		14	А
Power Dissipation, continuous @ T _C = 25°C	P _D		125	W
Input Voltage, differential	V _{IN (Diff)}	-20	+20	V
Input Voltage, common mode	V _{CM}	-V _S	+V _S	V
Temperature, pin solder, 10s max.			+260	°C
Temperature, junction ¹	T _J		+150	°C
Temperature Range, storage		-55	+125	°C
Operating Temperature Range, case	T _C	-40	+85	°C

^{1.} Long term operation at the maximum junction temperature will result in reduced product life. Derate internal power dissipation to achieve high MTTF.



The PA93 is constructed from MOSFET transistors. ESD handling procedures must be observed. CAUTION The substrate contains beryllia (BeO). Do not crush, machine, or subject to temperatures in excess of 850°C to avoid generating toxic fumes.

INPUT

Parameter	Test Conditions	Min	Тур	Max	Units
Offset Voltage, initial			2	10	mV
Offset Voltage vs. Temperature	Full temp range		15	50	μV/°C
Offset Voltage vs. Supply			10	25	μV/V
Offset Voltage vs. Time			75		μV/kh
Bias Current, initial			200	2000	рА
Bias Current vs. Supply			4		pA/V
Offset Current, initial			50	500	рА
Input Impedance, DC			10 ¹¹		Ω
Input Capacitance			4		pF
Common Mode Voltage Range ¹		±Vs ∓15			V
Common Mode Rejection, DC	V _{CM} = ±90V	80	98		dB
Noise	100 kHz BW, $R_S = 1 k\Omega$, $C_C = 10pF$		1		μV RMS

^{1.} $+V_S$ and $-V_S$ denote the positive and negative power supply rail respectively.



GAIN

Parameter	Test Conditions	Min	Тур	Max	Units
Open Loop @ 15 Hz	$R_L = 2 k\Omega$, $C_C = 10pF$	94	111		dB
Gain Bandwidth Product @ 1 MHz	$R_L = 2 k\Omega$, $C_C = 10pF$		12		MHz
Power Bandwidth	$R_L = 2 k\Omega$, $C_C = 10pF$		30		kHz
Phase Margin	Full temp range		60		0

OUTPUT

Parameter	Test Conditions	Min	Тур	Max	Units
Voltage Swing ¹	I _{OUT} = 8A	±V _S ∓12	±V _S ∓10		V
Current, continuous		8			Α
Slew Rate, A _V = 100	C _C = 10pF		50		V/µs
Capacitive Load, A _V = +1	Full temp range	1			nF
Settling Time to 0.1%	C _C = 10pF, 2V step		1		μs
Resistance, no load			10		Ω

^{1.} $+V_S$ and $-V_S$ denote the positive and negative power supply rail respectively.

POWER SUPPLY

Parameter	Test Conditions	Min	Тур	Max	Units
Voltage ¹		±40	±150	±200	V
Current, quiescent			10	14	mA

^{1.} Derate max supply rating 0.625 V/°C below 25°C case. No derating needed above 25°C case.

THERMAL

Parameter	Test Conditions	Min	Тур	Max	Units
Resistance, AC, junction to case ¹	Full temp range, F > 60 Hz			0.7	°C/W
Resistance, DC, junction to case	Full temp range, F < 60 Hz			1	°C/W
Resistance, junction to air Full temp range			30		°C/W
Temperature Range, case Meets full range specifications		-25		+85	°C

^{1.} Rating applies if the output current alternates between both output transistors at a rate faster than 60 Hz.



TYPICAL PERFORMANCE GRAPHS

Figure 4: Power Derating

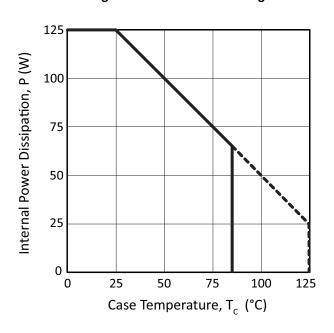


Figure 6: Small Signal Response

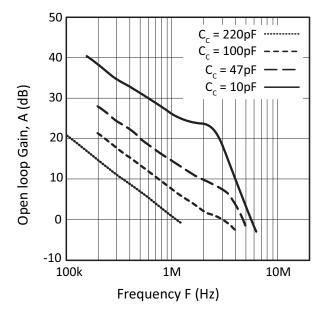


Figure 5: Normalized Quiescent Current

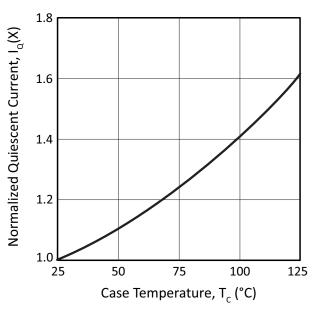


Figure 7: Phase Response

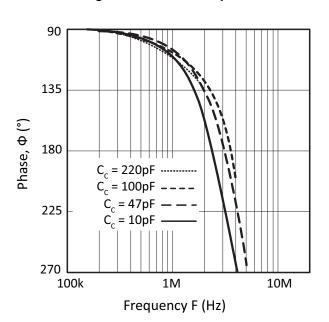




Figure 8: Output Voltage Swing

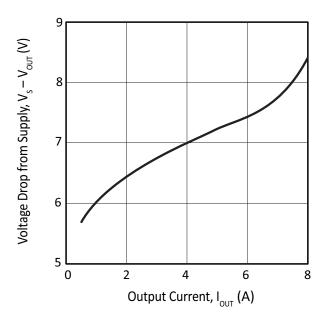


Figure 10: Slew Rate

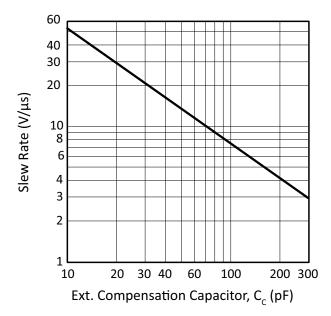


Figure 9: Power Response

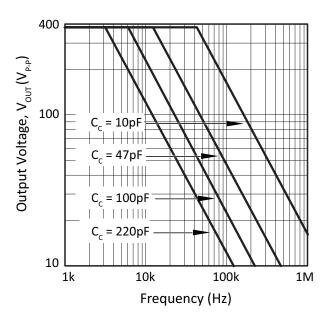


Figure 11: Harmonic Distortion

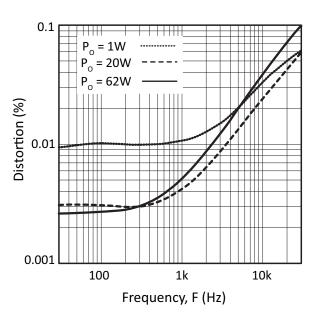




Figure 12: Input Noise Voltage

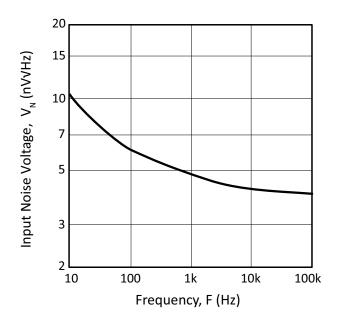
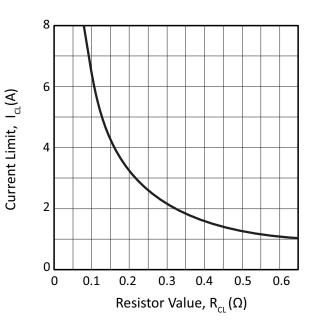


Figure 13: Current Limit





SAFE OPERATING AREA (SOA)

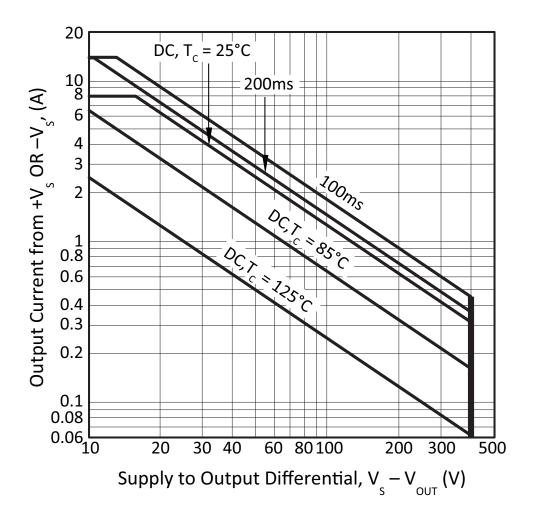
The safe operating area curves define the maximum additional internal power dissipation the amplifier can tolerate when it produces the necessary output to drive an external load.

The MOSFET output stage of this power operational amplifier has two distinct limitations:

- 1. The current handling capability of the MOSFET geometry and the wire bonds.
- 2. The junction temperature of the output MOSFETs.

Note: The output stage is protected against transient flyback. However, for protection against sustained, high energy flyback, external fast-recovery diodes should be used.

Figure 14: SOA





GENERAL

Please read Application Note 1 "General Operating Considerations" which covers stability, supplies, heat sinking, mounting, current limit, SOA interpretation, and specification interpretation. Visit www.apexanalog.com for Apex Microtechnology's complete Application Notes library, Technical Seminar Workbook, and Evaluation Kits.

TYPICAL APPLICATION

LOW POWER, PIEZOELECTRIC POSITIONING

Piezo positioning may be applied to the focusing of segmented mirror systems. The composite mirror may be composed of hundreds of elements, each requiring focusing under computer control. In such complex systems the PA93 reduces the costs of power supplies and cooling with its advantages of low cost and low quiescent power consumption while increasing circuit density with the SIP package.

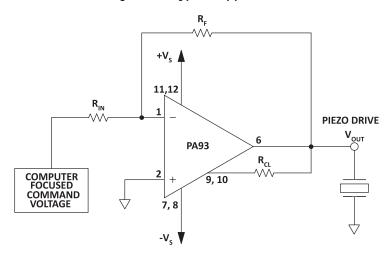


Figure 15: Typical Application

PHASE COMPENSATION

Gain	c _c *	$R_{\mathbb{C}}$
≥1	220pF	100 Ω
≥2	100pF	100 Ω
≥4	47pF	0 Ω
≥17	10pF	0 Ω

^{*} C_C Never to be <10pF. C_C to be rated for the full supply voltage + V_S to - V_S . Use ceramic NPO (COG) type.

STABILITY

The PA93 is externally compensated and performance can be tailored to the application. Use the graphs of small signal response and power response as a guide. The compensation capacitor C_C must be rated at 500V working voltage. An NPO capacitor is recommended. The compensation network C_CR_C must be mounted closely to the amplifier pins 4 and 5 to avoid spurious oscillation.



CURRENT LIMIT

For proper operation, the current limit resistor (R_{CL}) must be connected as shown in the external connection diagram. For optimum reliability the resistor value should be set as high as possible. The value is calculated as follows; with the maximum practical value of 16 ohms.

$$R_{CL}(\Omega) = \frac{0.65V}{I_{CL}(A)}$$

INPUT PROTECTION

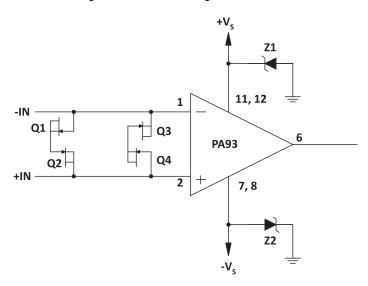
Although the PA93 can withstand differential voltages up to ± 20 V, additional external protection is recommended. Low leakage, low capacitance JFETs connected as diodes are recommended (e.g. 2N4416, Q1-Q4 in Figure 16). The differential input voltage will be clamped to ± 1.4 V. This is sufficient overdrive to produce maximum power bandwidth.

POWER SUPPLY PROTECTION

Unidirectional zener diode transient suppressors are recommended as protection on the supply pins. See Figure 16. The zeners clamp transients to voltages within the power supply rating and also clamp power supply reversals to ground. Whether the zeners are used or not, the system power supply should be evaluated for transient performance including power-on overshoot and power-off polarity reversals as well as line regulation.

Conditions which can cause open circuits or polarity reversals on either power supply rail should be avoided or protected against. Reversals or opens on the negative supply rail is known to induce input stage failure. Unidirectional transzorbs prevent this, and it is desirable that they be both electrically and physically as close to the amplifier as possible.

Figure 16: Over voltage Protection



PA93



QUIESCENT CURRENT REDUCTION

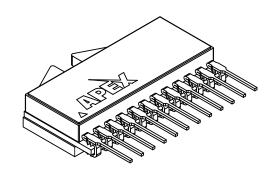
When pin 3 (I_Q) is shorted to pin 5 (C_C) the AB biasing of the output stage is disabled. This lowers quiescent power but also raises distortion since the output stage is then class C biased. The output stage bias current is nominally set at 1mA. Pin 3 may be left open if not used.

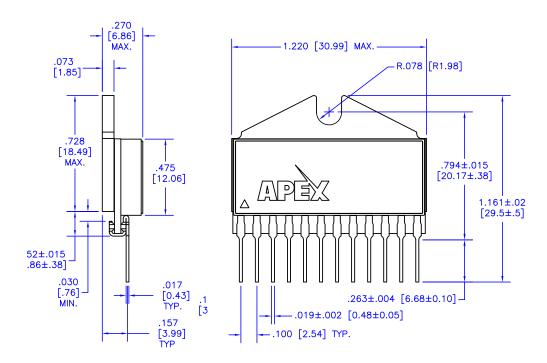


PACKAGE OPTIONS

Part Number	Apex Package Style	Description
PA93	DP	12-Pin SIP
PA93EE	EE	12-Pin SIP w/ formed leads

PACKAGE STYLE DP



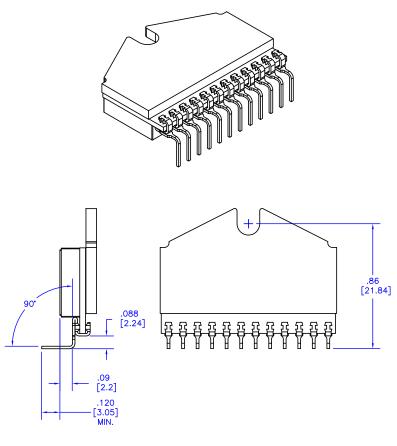


NOTES:

- Dimensions are inches & [mm].
 Triangle on lid denotes pin 1.
 Pins: Alloy 510 phosphor bronze plated with matte tin (150 300μ") over nickel (50 μ" max.) underplate.
 Package: Vectra liquid crystal polymer, black
 Epoxy-sealed & ultrasonically welded non-hermetic package.
 Package weight: .367 oz. [11.41 g]



PACKAGE STYLE EE



NOTES:

- 1. Dimensions are inches & [mm].
- 2. For other dimensions and information on this package with unformed leads, see package DP.

NEED TECHNICAL HELP? CONTACT APEX SUPPORT!

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